



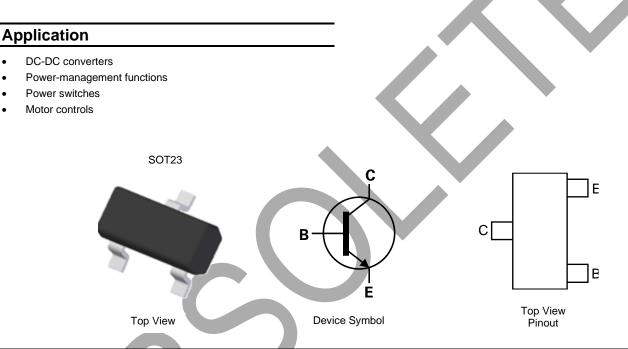
20V NPN LOW SATURATION TRANSISTOR IN SOT23

Features

- $BV_{CEO} = 20V$
- Low Saturation Voltage V_{CE(sat)} < 12mV @ 100mA
- I_C = 2.5A Continuous Current
- R_{sat} = 40m Ω for a Low Equivalent On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

Part Number	Paskage	Marking	Reel Size (inches)	Tape Width (mm)	Pacl	Packing	
Fart Nulliber	Package	age Marking Reel Size (inches)	Reel Size (Inches)	rape width (mm)	Qty.	Carrier	
ZXT11N20DFTA	SOT23	2N0	7	8	3000	Reel	

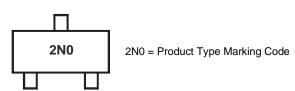
Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and 2 Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	40	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	Vebo	7.5	V
Continuous Collector Current	lc	2.5	A
Peak Pulse Collector Current (Single Pulse)	I _{CM}	5	A
Base Current	IB	500	mA

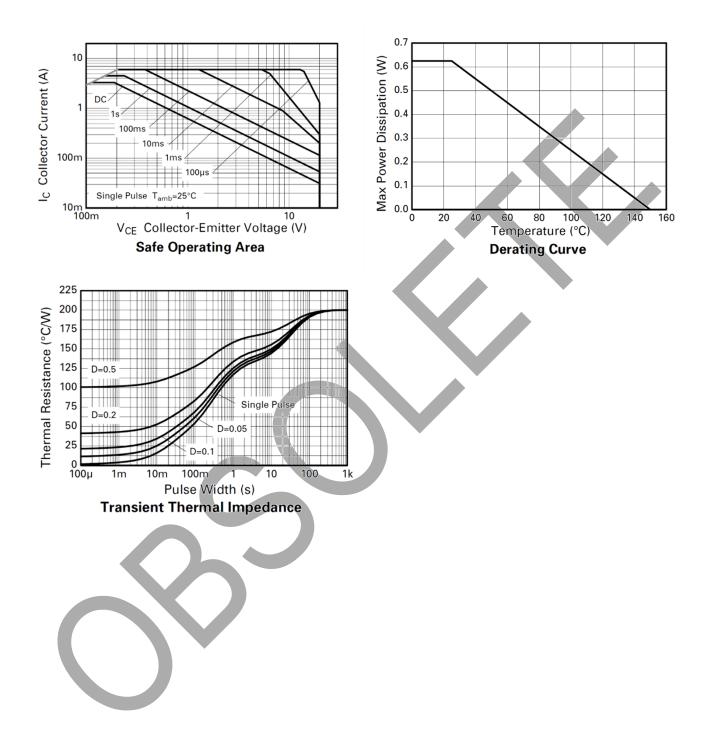
Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Linear Derating Factor	PD	625 5	W mW/°C
Power Dissipation (Note 6) Linear Derating Factor	PD	806 6.4	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	Reja	200	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	155	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

5. For a device surface-mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.
6. Same as Note 5, except the device is measured at t < 5 seconds. Notes:



Thermal Characteristics and Derating Information





Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

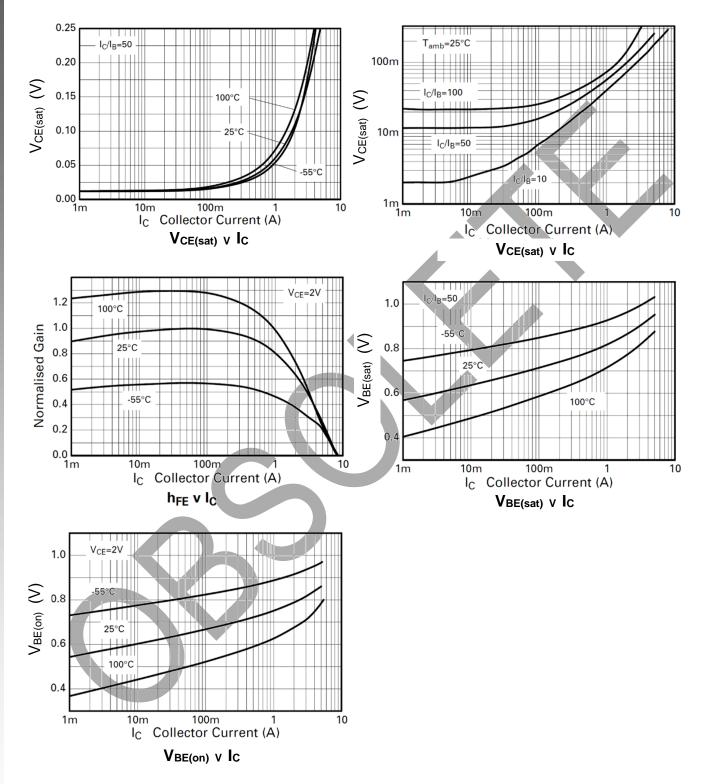
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	ВУсво	40	—	_	V	Ic = 100μA	
Collector-Emitter Breakdown Voltage (Note 7)	BVCEO	20	_	—	V	Ic = 10mA	
Emitter-Base Breakdown Voltage	BVEBO	7.5	_	_	V	I _E = 100μA	
Collector Cutoff Current	Ісво	—	—	100	nA	Vcb = 32V	
Collector Emitter Cutoff Current	ICES	—	—	100	nA	VCES = 32V	
Emitter Cutoff Current	IEBO	—	—	100	nA	Veb = 6V	
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}		7 65 40 90	12 100 60 130	mV	$Ic = 100mA, I_B = 10mA$ $Ic = 1A, I_B = 10mA$ $Ic = 1A, I_B = 100mA$ $Ic = 1A, I_B = 100mA$ $Ic = 2.5A, I_B = 250mA$	
Base-Emitter Saturation Voltage (Note 7)	VBE(sat)	_	0.9	1.0	V	Ic = 2.5A, I _B = 250mA	
Base-Emitter Turn-On Voltage (Note 7)	VBE(on)	_	0.85	1.0	V	IC = 2.5A, VCE = 2V	
DC Current Gain (Note 7)	hfe	200 300 250 150 100		900	-	Ic = 10mA, VcE = 2V Ic = 100mA, VcE = 2V Ic = 1A, VcE = 2V Ic = 3A, VcE = 2V Ic = 5A, VcE = 2V	
Transitional Frequency	fT	_	160		MHz	Ic = 50mA, Vce = 10V f = 50MHz	
Output Capacitance	C _{obo}	_	20	—	pF	V _{CB} = 10V, f = 1MHz	
Switching Time	t _{on} t _{off}	_	122 295	- /	ns	Ic = 2A, Vcc = 10V I _{B1} = -I _{B2} = 20mA	

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

ZXT11N20DF Document number: DS33629 Rev. 3 - 4



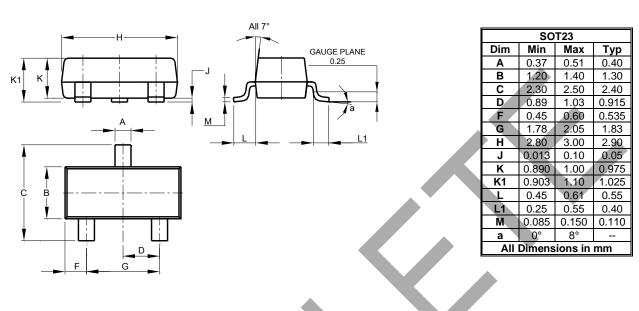
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Dimensions	Value (in mm)		
С	2.0		
Х	0.8		
X1	1.35		
Y	0.9		
Y1	2.9		

SOT23



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